

Question Bank (G scheme)

Name of subject: Principles of Digital Techniques

Subject code: 17320

Semester: III

Unit Test: II

Course: EJ/IS/IE

Chapter.3: Combinational Logic Circuit (14 Marks)

3 marks

- 1) Implement the following using MUX
 - a. $Y = \sum m(2, 3, 5, 6)$
- 2) Give advantage of MUX.
- 3) Differentiate between MUX & DEMUX
- 4) What is Tristate buffer? Draw its symbol & IC NO.

4 marks

- 5) What is Decoder? How Demux act as a Decoder.
- 6) Draw ckt dig of 1:4 Demux using logic gate.
- 7) Draw functional diagram & logic diagram of half adder with truth table

Chapter.4: Sequential Logic Circuit (24 Marks)

3 marks

- 8) Draw RS latch using NAND gate & write truth table.
- 9) Explain the use of Preset & Clear terminal of F/F.
- 10) Write the excitation table for D & T F/F
- 11) Draw block diagram of IC 7490.

4 marks

- 12) Differentiate between Sequential Logic & Combinational Logic.
- 13) Draw 3 bit Asynchronous down counter write truth table.
- 14) What is Race around condition & how it is eliminated?
- 15) Draw & explain SISO shift register.
- 16) Explain with diagram 3 bit ring counter using D F/F

Chapter.5: Data Converter (16 Marks)

3 marks

- 17) What is the necessity of Data converter? Write the types of data converter
- 18) Compare R-2R & binary weighted register (Any 3 points).
- 19) Define.
 - a. Accuracy

- b. Resolution
- c. Conversion time

4 marks

- 20) Draw ckt for 3 bit binary weighted DAC.
- 21) Draw & Explain Successive approximation ADC.
- 22) Calculate Analog o/p of 4 bit DAC & digital i/p is 1011 Assume $V_{fs} = 5v$.

Chapter.6: Memories (10 marks)

3 marks

- 23) Define memory? Write down types of memory.

4 marks

- 24) Draw static RAM cell (TTL) .Explain its operation.
- 25) Write difference between EPROM & Flash Memory.